NSN 5961-01-031-4774

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Inclosure Material:

Metal

Overall Length:

0.405 inches

Overall Height:

0.127 inches

Overall Width:

0.263 inches

End Application:

Anfsq111

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

35.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 35.0

breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 5.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

750.00 milliamperes source cutoff current

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

135.0 degrees celsius junction

Special Features:

Heat sink included; junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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